

Product Preview

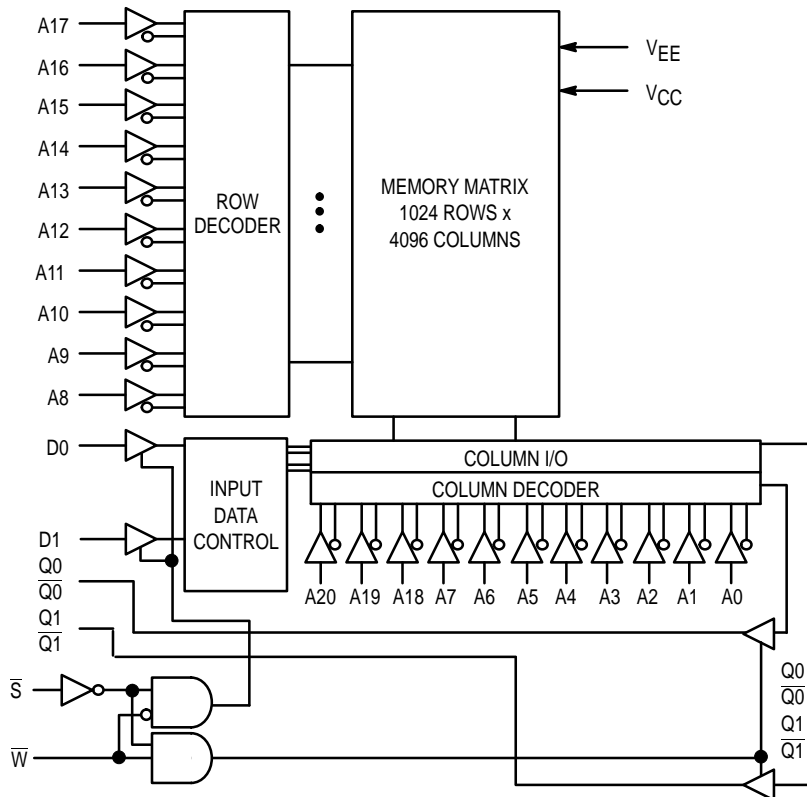
2M x 2 Bit Fast Static Random Access Memory with ECL I/O

The MCM101525 is a 4,194,304 bit static random access memory organized as 2,097,152 words of 2 bits. This device features complementary outputs. This circuit is fabricated using high performance silicon-gate BiCMOS technology. Asynchronous design eliminates the need for external clocks or timing strobes.

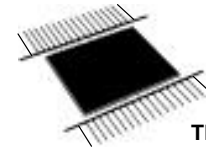
The MCM101525 is available in a 400 mil, 36 lead TAB.

- Fast Access Times: 12, 15 ns
- Equal Address and Chip Select Access Time
- Power Operation: – 195 mA Maximum, Active AC

BLOCK DIAGRAM



MCM101525



TB PACKAGE
400 MIL TAB
CASE 984A-01

PIN ASSIGNMENT

A10	1	36	A1
A11	2	35	A2
A12	3	34	A3
A13	4	33	A8
A14	5	32	A19
S-bar	6	31	NC
D0	7	30	A20
Q0	8	29	Q1-bar
VCC	9	28	VEE
VEE	10	27	VCC
Q0-bar	11	26	Q1
VEE	12	25	D1
W-bar	13	24	NC
A0	14	23	A9
A15	15	22	A4
A16	16	21	A5
A17	17	20	A6
A18	18	19	A7

PIN NAMES

A0 – A20	Address Inputs	W-bar	Write Enable
S-bar	Chip Select	D0 – D1	Data Input
Q0 – Q1	Data Output	Q0 and Q1-bar	Complementary Data Out
NC	No Connection	VEE	Power Supply
VCC	Ground		

This document contains information on a new product under development. Motorola reserves the right to change or discontinue this product without notice.

TRUTH TABLE (X = Don't Care)

\bar{S}	\bar{W}	Operation	Data	Output	Current
H	X	Not Enabled	X	L	—
L	H	Read	X	Q/ \bar{Q}	I_{EE}
L	L	Write	X	L	I_{EE}

ABSOLUTE MAXIMUM RATINGS (See Note)

Rating	Symbol	Value	Unit
V_{EE} Pin Potential (to Ground)	V_{EE}	- 7.0 to + 0.5	V
Voltage Relative to V_{CC} for Any Pin Except V_{EE}	V_{in}, V_{out}	$V_{EE} - 0.5$ to + 0.5	V
Output Current (per I/O)	I_{out}	- 50	mA
Power Dissipation	P_D	2.0	W
Temperature Under Bias	T_{bias}	- 30 to + 85	°C
Operating Temperature	T_J	0 to + 60	°C
Storage Temperature — Plastic	T_{stg}	- 55 to + 125	°C

NOTE: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to the OPERATING CONDITIONS. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to these high impedance circuits.

This BiCMOS memory circuit has been designed to meet the dc and ac specifications shown in the tables, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow of at least 500 linear feet per minute is maintained.

DC OPERATING CONDITIONS AND CHARACTERISTICS

($V_{CC} = 0$ V, $V_{EE} = -5.2$ V \pm 5%, $T_J = 0$ to + 60°C, Unless Otherwise Noted)

DC OPERATING CONDITIONS AND SUPPLY CURRENTS

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage (Operating Voltage Range)	V_{EE}	- 5.46	- 5.2	- 4.94	V
Input High Voltage	V_{IH}	- 1165	—	- 880	mV
Input Low Voltage	V_{IL}	- 1810	—	- 1475	mV
Output High Voltage	V_{OH}	- 1025	—	- 880	mV
Output Low Voltage	V_{OL}	- 1810	—	- 1620	mV
Input Low Current	I_{IL}	- 50	—	—	μ A
Input High Current	I_{IH}	—	—	220	μ A
Chip Select Input Low Current	$I_{IL}(CS)$	0.5	—	170	μ A
Operating Power Supply Current: $t_{AVAV} = 20$ ns (All Outputs Open)*	I_{EE}	—	—	- 195	mA
Quiescent Power Supply Current: $f_0 = 0$ MHz (Outputs Open)	I_{EEQ}	—	—	- 150	mA
Voltage Compensation (V_{OH})	$\Delta V_{OH}/\Delta V_{EE}$	± 35 mV/V @ - 4.94 to - 5.46 V			
Voltage Compensation (V_{OL})	$\Delta V_{OL}/\Delta V_{EE}$	± 60 mV/V @ - 4.94 to - 5.46 V			

* Address Increment

RISE/FALL TIME CHARACTERISTICS

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Rise Time	t_r	20% to 80%	0.5	1.0	1.5	ns
Output Fall Time	t_f	20% to 80%	0.5	1.0	1.5	ns

CAPACITANCE ($f = 1.0$ MHz, $T_A = 25^\circ$ C, Periodically Sampled Rather Than 100% Tested)

Parameter	Symbol	Typ	Max	Unit	
Input Capacitance	Address and Data \bar{S}, \bar{W}	C_{in}	3.5	7	pF
	\bar{Q}, Q	C_{ck}	4	7	pF
Output Capacitance	\bar{Q}, Q	C_{out}	4	8	pF

AC OPERATING CONDITIONS AND CHARACTERISTICS
 (V_{EE} = - 5.2 V ± 5%, V_{CC} = 0 V, T_J = 0 to +60°C, Unless Otherwise Noted)

Input Pulse Levels - 1.7 V to - 0.9 V (See Figure 1) Output Timing Measurement Reference Level .. V_{OH} = - 1165 mV
 Input Rise/Fall Time 1 ns V_{OL} = - 1475 mV
 Input Timing Measurement Reference Level 50% Output Load (AC Test Circuit) See Figure 2

READ CYCLE TIMING (See Notes 1 and 2)

Parameter	Symbol	MCM101525-12		MCM101525-15		Unit	Notes
		Min	Max	Min	Max		
Read Cycle Time	t _{AVAV}	12	—	15	—	ns	2, 3
Address Access Time	t _{AVQV}	—	12	—	15	ns	
Chip Select Access Time	t _{SLQV}	—	12	—	15	ns	6
Select High to Output Low	t _{SHQL}	0	8	0	9	ns	
Output Hold from Address Change	t _{AXQX}	4	—	4	—	ns	
Power Up Time	t _{SLIEEH}	0	—	0	—	ns	4
Power Down Time	t _{SHIEEL}	—	12	—	15	ns	4

NOTES:

1. \bar{W} is high for read cycle.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies during read and write cycles.
3. All read cycle timings are referenced from the last valid address to the first transitioning address.
4. This parameter is sampled and not 100% tested.
5. Device is continuously selected ($\bar{S} \leq V_{IL}$).
6. Addresses valid prior to or coincident with \bar{S} going low.

AC TEST CONDITIONS

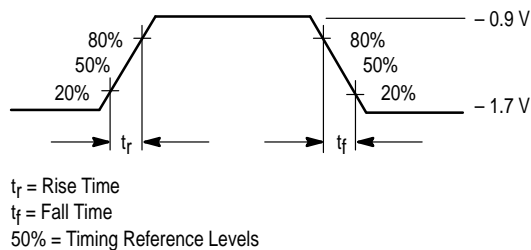


Figure 1. Input Levels

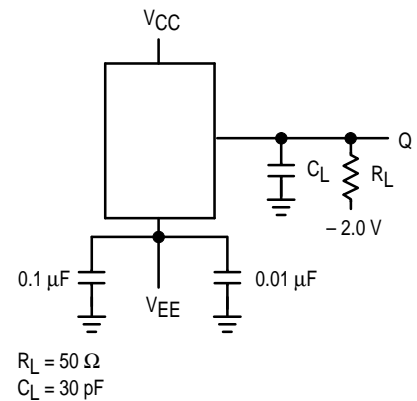
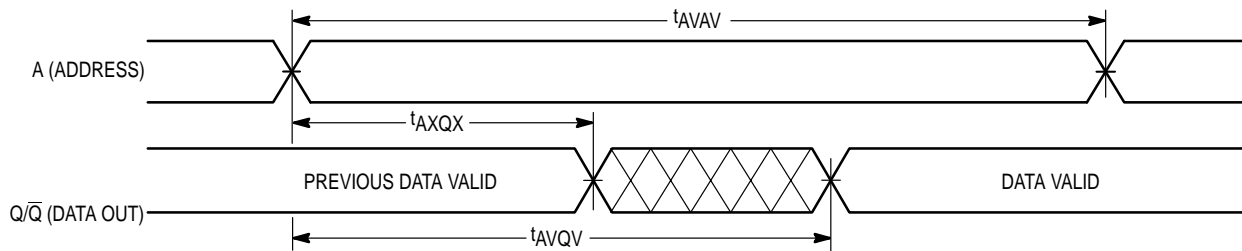
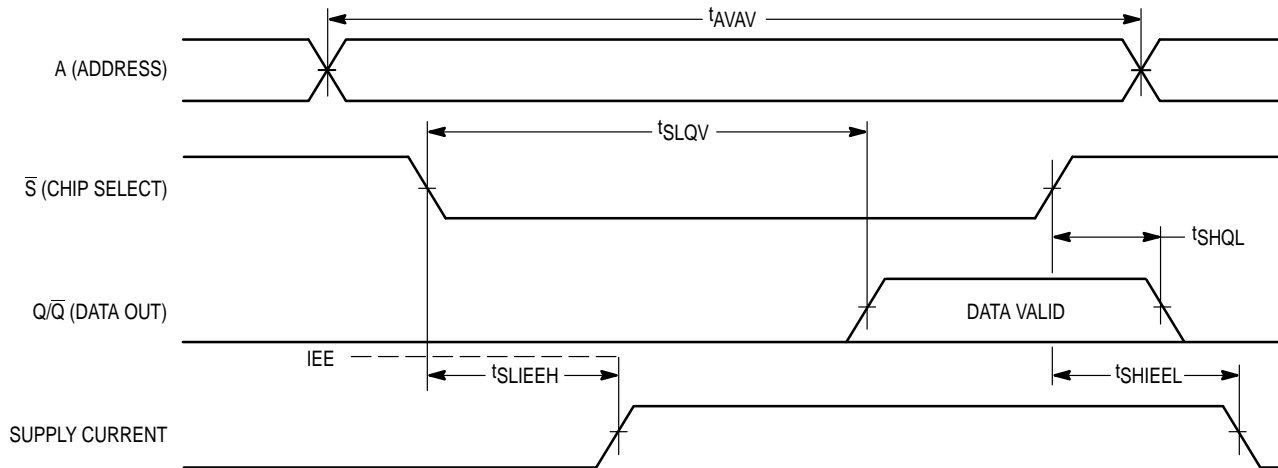


Figure 2. AC Test Circuit

READ CYCLE 1 (See Notes 1, 2, and 5)



READ CYCLE 2 (See Note 6)

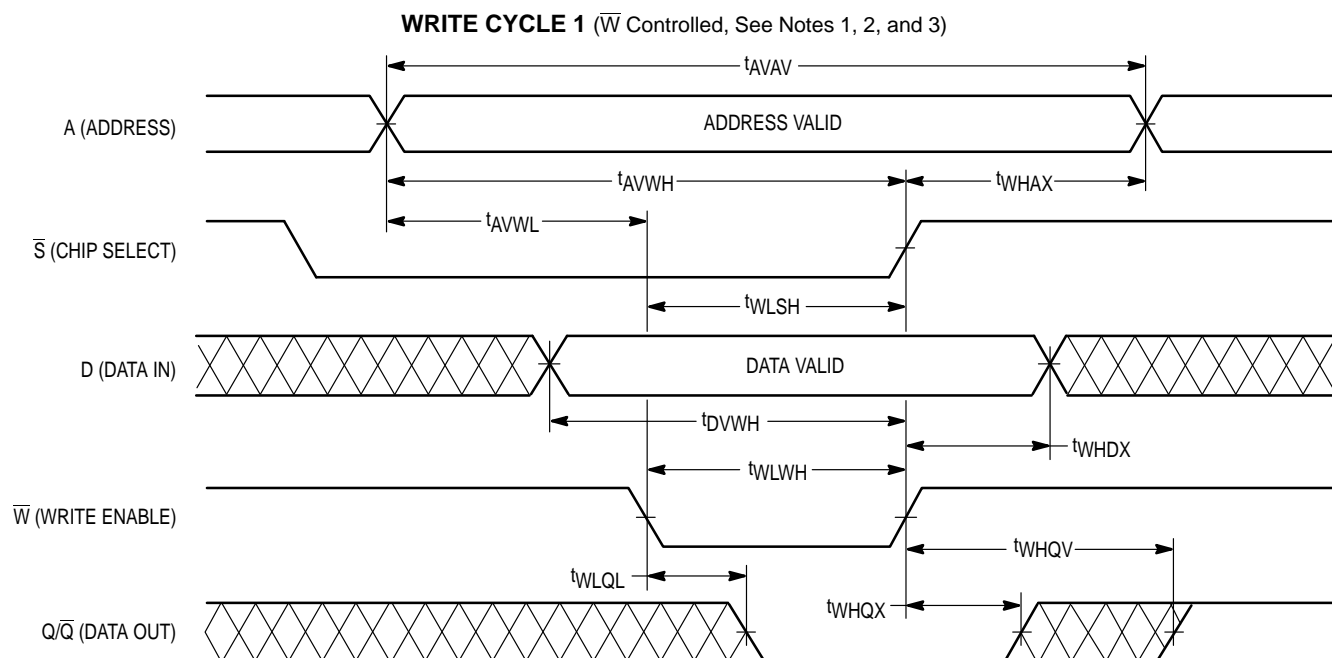



WRITE CYCLE 1 (\overline{W} Controlled, See Notes 1 and 2)

Parameter	Symbol	MCM101525-12		MCM101525-15		Unit	Notes
		Min	Max	Min	Max		
Write Cycle Time	t_{AVAV}	12	—	15	—	ns	3
Address Setup Time	t_{AVWL}	1	—	1	—	ns	
Address Valid to End of Write	t_{AVWH}	9	—	10	—	ns	
Write Pulse Width	t_{WLWH} , t_{WLSH}	8	—	9	—	ns	
Data Valid to End of Write	t_{DVWH}	8	—	9	—	ns	
Data Hold Time	t_{WHDX}	1	—	1	—	ns	
Write High to Output Active	t_{WHQX}	4	—	4	—	ns	4
Write High to Output Valid	t_{WHQV}	—	13	—	16	ns	
Write Recovery Time	t_{WHAX}	1	—	1	—	ns	
Write Low to Output Low	t_{WLQL}	0	8	0	9	ns	

NOTES:

1. A write occurs during the overlap of \overline{S} low and \overline{W} low.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies during read and write cycles.
3. All write cycle timings are referenced from the last valid address to the first transitioning address.
4. This parameter is sampled and not 100% tested.



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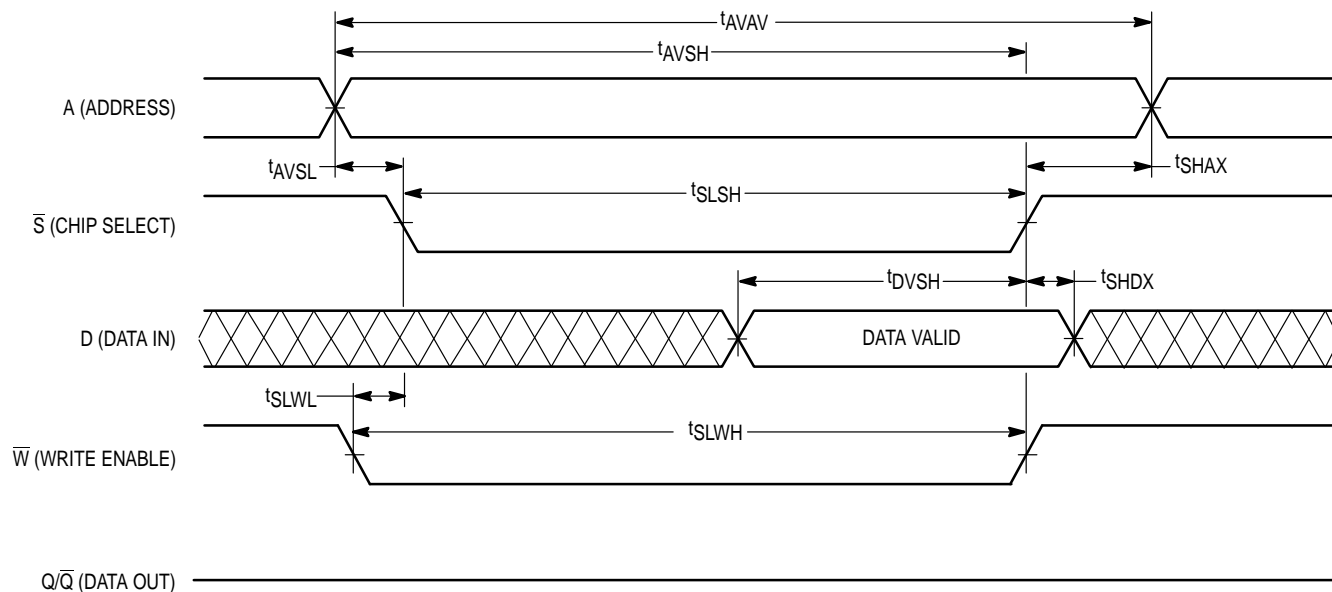
WRITE CYCLE 2 (\bar{S} Controlled, See Notes 1 and 2)

Parameter	Symbol	MCM101525-12		MCM101525-15		Unit	Notes
		Min	Max	Min	Max		
Write Cycle Time	t_{AVAV}	12	—	15	—	ns	3
Address Setup Time	t_{AVSL}	1	—	1	—	ns	
Address Valid to End of Write	t_{AVSH}	9	—	10	—	ns	
Write Pulse Width	t_{SLSH} (\bar{S}) t_{SLWH} (\bar{W})	8	—	9	—	ns	
Data Valid to End of Write	t_{DVSH}	8	—	9	—	ns	
Chip Select Set-Up Time	t_{SLWL}	0	—	0	—	ns	
Data Hold Time	t_{SHDX}	1	—	1	—	ns	
Write Recovery Time	t_{SHAX}	1	—	1	—	ns	

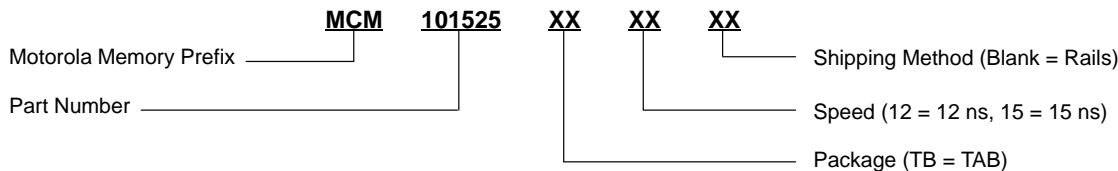
NOTES:

1. A write occurs during the overlap of \bar{S} low and \bar{W} low.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies during read and write cycles.
3. All write cycle timings are referenced from the last valid address to the first transitioning address.

WRITE CYCLE 2 (\bar{S} Controlled, See Notes 1 and 2)



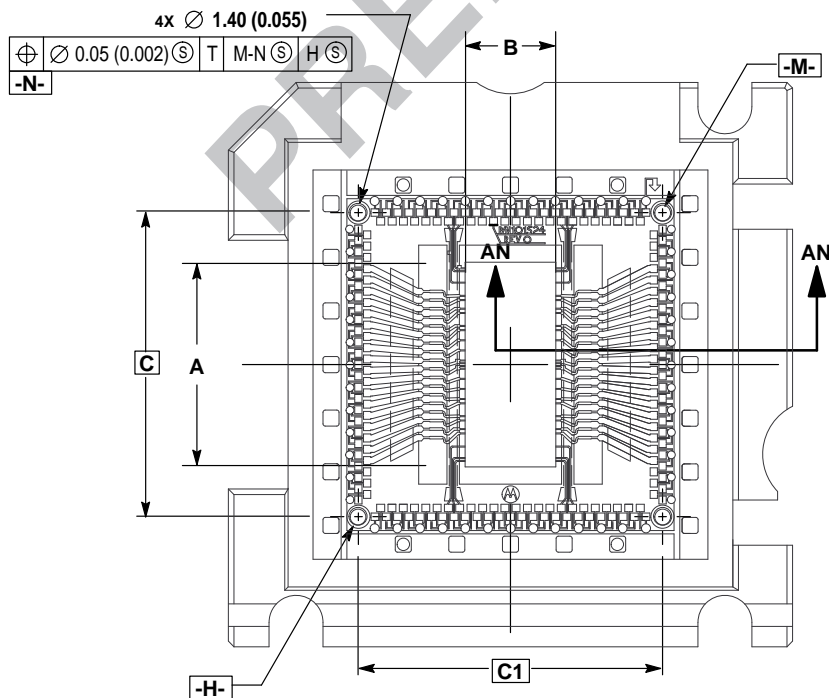
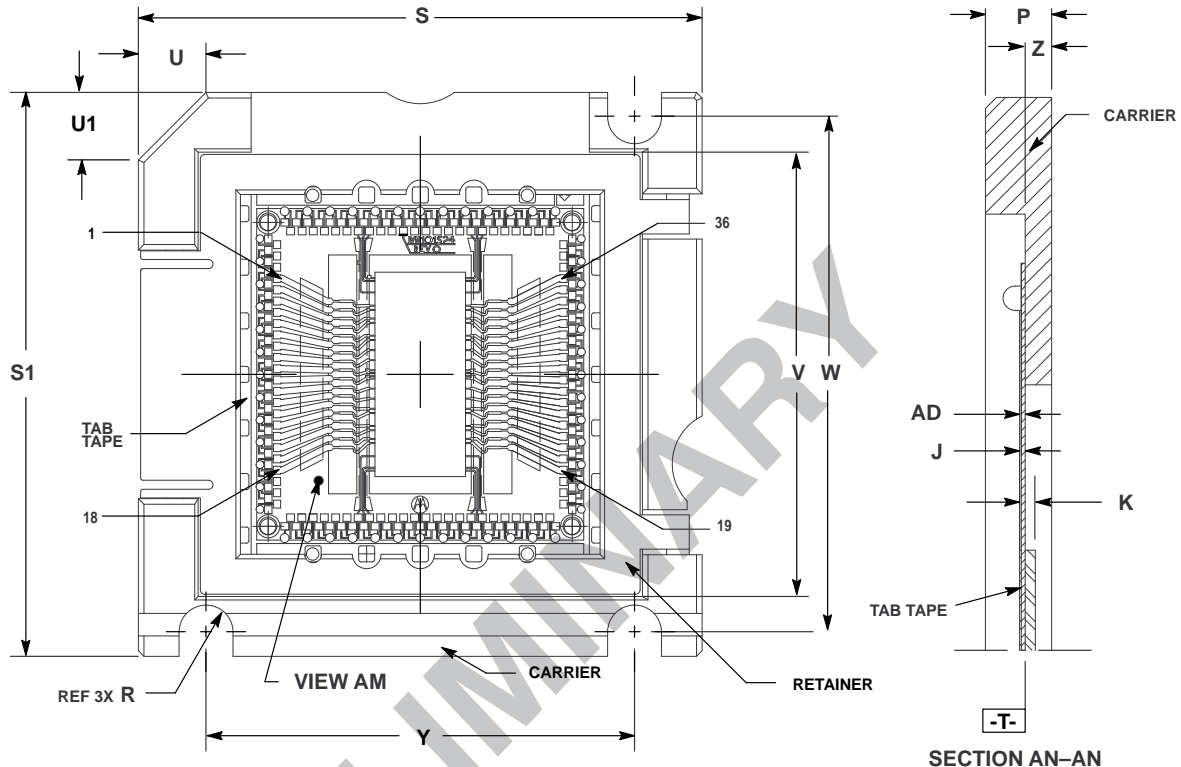
ORDERING INFORMATION
(Order by Full Part Number)



Full Part Numbers — MCM101525TB12
MCM101525TB15

PACKAGE DIMENSIONS

TB PACKAGE
400 MIL TAB
CASE 984A-01

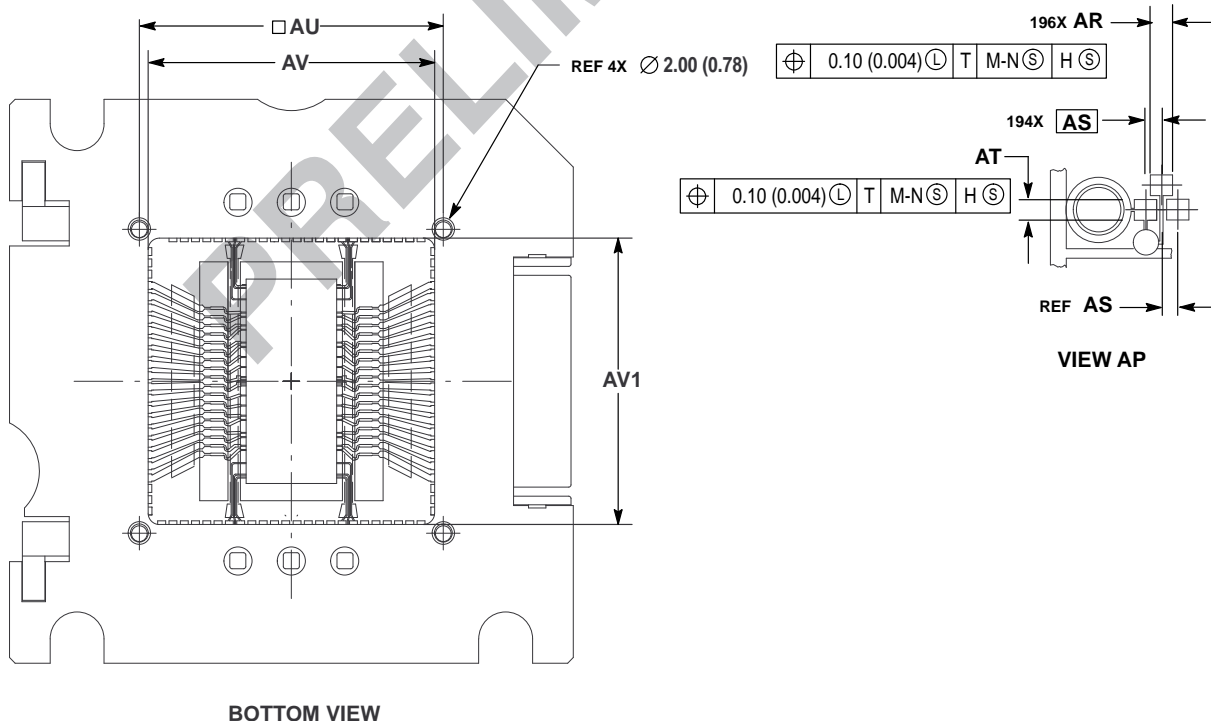
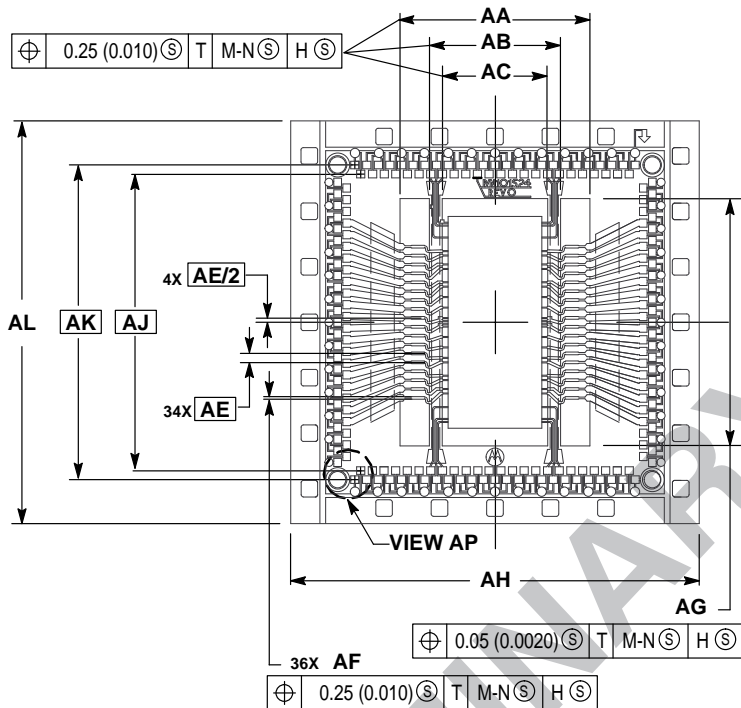


VIEW AM
TAPE CARRIER RETAINER ELIMINATED
FROM VIEW FOR CLARITY

- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	18.14 REF		0.714 REF	
B	8.03 REF		0.316 REF	
C	26.95 BSC		1.061 BSC	
C1	26.95 BSC		1.061 BSC	
J	—	0.25	—	0.010
K	—	0.71	—	0.028
P	3.00 REF		0.118 REF	
R	2.39 REF		0.094 REF	
S	50.00 REF		1.969 REF	
S1	50.00 REF		1.969 REF	
U	6.00 REF		0.236 REF	
U1	6.00 REF		0.236 REF	
V	39.40 REF		1.551 REF	
W	45.68 REF		1.798 REF	
Y	38.00 REF		1.496 REF	
Z	1.15	1.25	0.045	0.049
AA	16.21	16.31	0.638	0.642
AB	11.20	11.30	0.441	0.445
AC	8.99	9.09	0.354	0.358
AD	0.15	0.21	0.006	0.008
AE	0.762 BSC		0.030 BSC	
AF	0.18	0.28	0.007	0.011
AG	21.31	21.24	0.832	0.836
AH	35.00 REF		1.378 REF	
AJ	25.40 REF		1.000 REF	
AK	26.95 BSC		1.061 BSC	
AL	34.98 REF		1.377 REF	
AR	0.65	0.75	0.026	0.030
AS	0.50 BSC		0.020 BSC	
AT	0.60	0.70	0.024	0.028
AU	26.95 REF		1.061 REF	
AV	25.35	25.45	0.998	1.002
AV1	25.35	25.45	0.998	1.002

TB PACKAGE
400 MIL TAB
CASE 984A-01 (cont.)



BOTTOM VIEW

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